

SD-C Series 450W Discrete Bidirectional TVS Diode

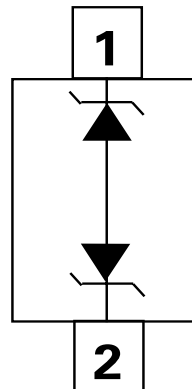


Description

The bidirectional SD-C series is designed to replace multilayer varistors (MLVs) in electronic equipment for low speed and DC applications. It will protect any sensitive equipment from damage due to electrostatic discharge (ESD) and other transient events.

The SD-C series can safely absorb repetitive ESD strikes at $\pm 30\text{kV}$ (contact discharge, IEC 61000-4-2) without performance degradation and safely dissipate 30A (SD05C) of 8/20 μs induced surge current (IEC61000-4-5) with very low clamping voltages.

Pinout and Functional Block Diagram



Features

- ESD, IEC61000-4-2, $\pm 30\text{kV}$ contact, $\pm 30\text{kV}$ air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 30A ($t_p=8/20\mu\text{s}$, SD05C)
- Low clamping voltage
- Low leakage current
- Small SOD323 package fits 0805 footprints
- AEC-Q101 qualified

Applications

- Switches / Buttons
- Test Equipment / Instrumentation
- Point-of-Sale Terminals
- Medical Equipment
- Notebooks / Desktops / Servers
- Computer Peripherals
- Automotive Electronics

Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
P_{pk}	Peak Pulse Power ($t_p=8/20\mu s$)	450	W
T_{OP}	Operating Temperature	-40 to 125	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

Notes:

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Thermal Information

Parameter	Rating	Units
Storage Temperature Range	-55 to 150	°C
Maximum Junction Temperature	150	°C
Maximum Lead Temperature (Soldering 20-40s)	260	°C

SD05C Electrical Characteristics ($T_{OP}=25^{\circ}C$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1\mu A$			5.0	V
Reverse Voltage Drop	V_R	$I_R = 1mA$	6.0			V
Leakage Current	I_{LEAK}	$V_R = 5V$			1.0	μA
Clamp Voltage ¹	V_C	$I_{PP} = 1A, t_p = 8/20\mu s, Fwd$			10.0	V
		$I_{PP} = 10A, t_p = 8/20\mu s, Fwd$			14.5	V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p = 100ns$, I/O to Ground		0.31		Ω
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$			30.0	A
ESD Withstand Voltage ¹	V_{ESD}	IEC61000-4-2 (Contact Discharge)	± 30			kV
		IEC61000-4-2 (Air Discharge)	± 30			kV
Diode Capacitance ¹	C_D	Reverse Bias=0V, $f=1MHz$			200	pF

SD12C Electrical Characteristics ($T_{OP}=25^{\circ}C$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1\mu A$			12.0	V
Reverse Voltage Drop	V_R	$I_R = 1mA$	13.3			V
Leakage Current	I_{LEAK}	$V_R = 12V$			1.0	μA
Clamp Voltage ¹	V_C	$I_{PP} = 1A, t_p = 8/20\mu s, Fwd$			18.5	V
		$I_{PP} = 10A, t_p = 8/20\mu s, Fwd$			23.0	V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p = 100ns$, I/O to Ground		0.41		Ω
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$			17.0	A
ESD Withstand Voltage ¹	V_{ESD}	IEC61000-4-2 (Contact Discharge)	± 30			kV
		IEC61000-4-2 (Air Discharge)	± 30			kV
Diode Capacitance ¹	C_{D-GND}	Reverse Bias=0V, $f=1MHz$			100	pF

SD15C Electrical Characteristics (T_{Op}=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V _{RWM}	I _R ≤ 1μA			15.0	V
Reverse Voltage Drop	V _R	I _R = 1mA	16.7			V
Leakage Current	I _{LEAK}	V _R = 15V			1.0	μA
Clamp Voltage ¹	V _C	I _{PP} = 1A, t _p = 8/20μs, Fwd			24.0	V
		I _{PP} = 10A, t _p = 8/20μs, Fwd			31.0	V
Dynamic Resistance ²	R _{DYN}	TLP, tp = 100ns, I/O to Ground		0.46		Ω
Peak Pulse Current	I _{PP}	t _p = 8/20μs			12.0	A
ESD Withstand Voltage ¹	V _{ESD}	IEC61000-4-2 (Contact Discharge)	±30			kV
		IEC61000-4-2 (Air Discharge)	±30			kV
Diode Capacitance ¹	C _{I/O-GND}	Reverse Bias = 0V, f = 1MHz			75	pF

SD24C Electrical Characteristics (T_{Op}=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V _{RWM}	I _R ≤ 1μA			24.0	V
Reverse Voltage Drop	V _R	I _R = 1mA	26.7			V
Leakage Current	I _{LEAK}	V _R = 24V			1.0	μA
Clamp Voltage ¹	V _C	I _{PP} = 1A, t _p = 8/20μs, Fwd			34.0	V
		I _{PP} = 5A, t _p = 8/20μs, Fwd			42.0	V
Dynamic Resistance ²	R _{DYN}	TLP, tp = 100ns, I/O to Ground		0.62		Ω
Peak Pulse Current	I _{PP}	t _p = 8/20μs			7.0	A
ESD Withstand Voltage ¹	V _{ESD}	IEC61000-4-2 (Contact Discharge)	±30			kV
		IEC61000-4-2 (Air Discharge)	±30			kV
Diode Capacitance ¹	C _{I/O-GND}	Reverse Bias = 0V, f = 1MHz			50	pF

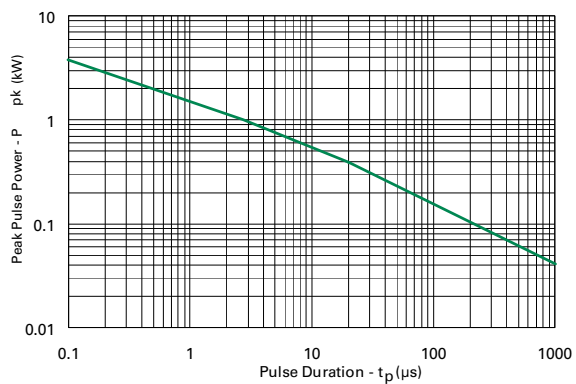
SD36C Electrical Characteristics (T_{Op}=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V _{RWM}	I _R ≤ 1μA			36.0	V
Reverse Voltage Drop	V _R	I _R = 1mA	40.0			V
Leakage Current	I _{LEAK}	V _R = 36V			1.0	μA
Clamp Voltage ¹	V _C	I _{PP} = 1A, t _p = 8/20μs, Fwd			50.0	V
		I _{PP} = 4A, t _p = 8/20μs, Fwd			60.0	V
Dynamic Resistance ²	R _{DYN}	TLP, tp = 100ns, I/O to Ground		0.68		Ω
Peak Pulse Current	I _{PP}	t _p = 8/20μs			5.0	A
ESD Withstand Voltage ¹	V _{ESD}	IEC61000-4-2 (Contact Discharge)	±30			kV
		IEC61000-4-2 (Air Discharge)	±30			kV
Diode Capacitance ¹	C _{I/O-GND}	Reverse Bias = 0V, f = 1MHz			30	pF

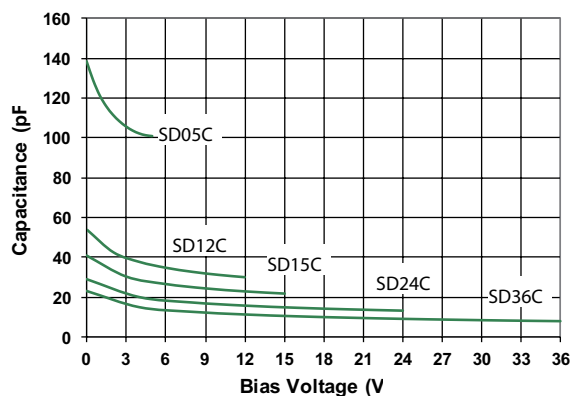
Note:

1. Parameter is guaranteed by design and/or device characterization.
2. Transmission Line Pulse (TLP) with 100ns width and 200ps rise time.

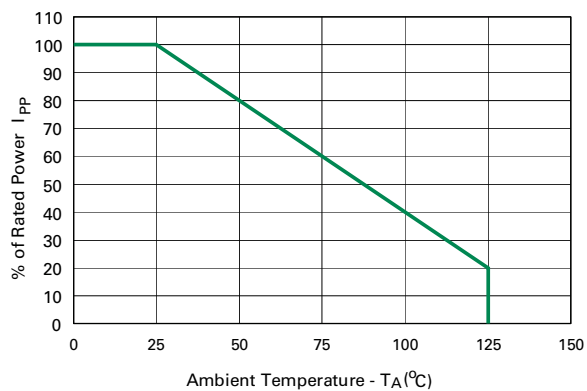
Non-Repetitive Peak Pulse Power vs. Pulse Time



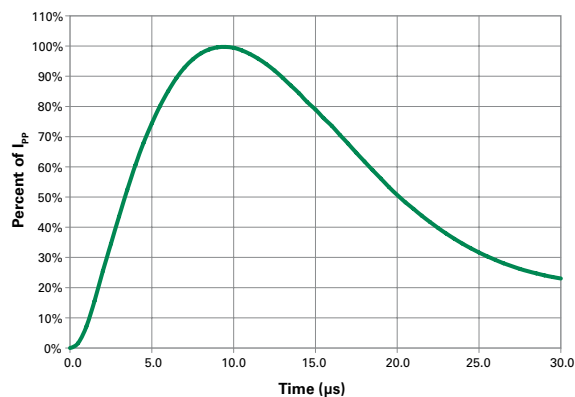
Capacitance vs. Bias



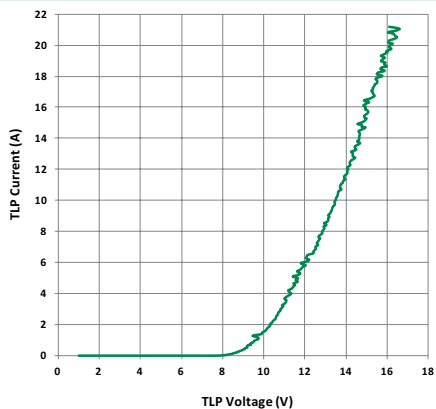
Power Derating Curve



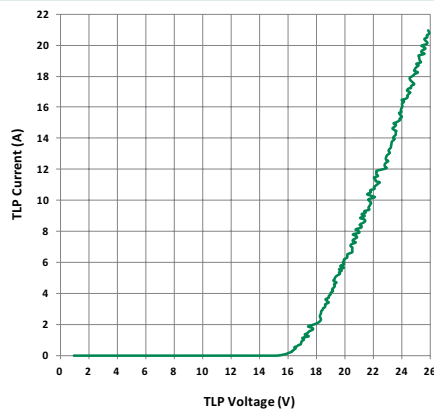
Pulse Waveform



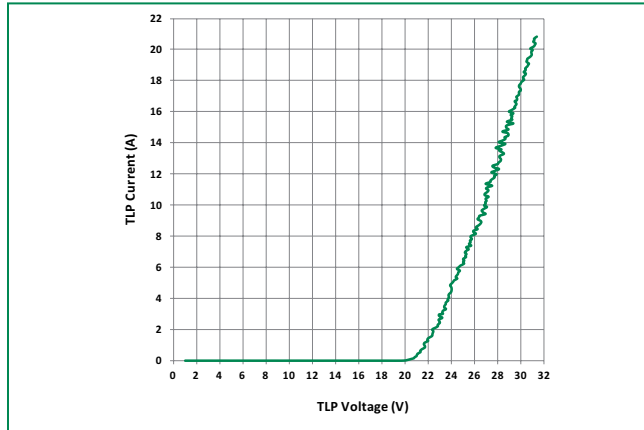
SD05C Transmission Line Pulsing(TLP) Plot



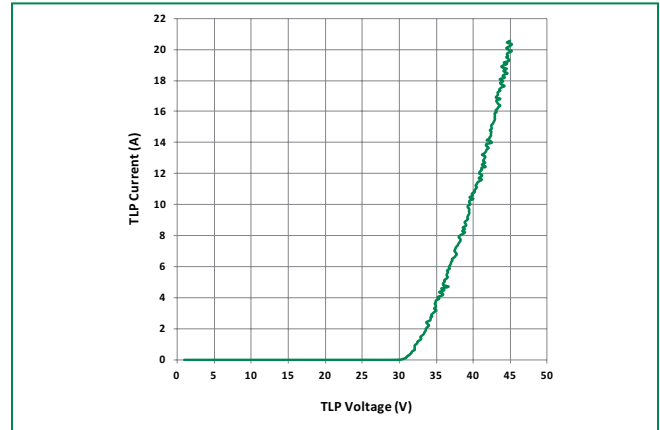
SD12C Transmission Line Pulsing(TLP) Plot



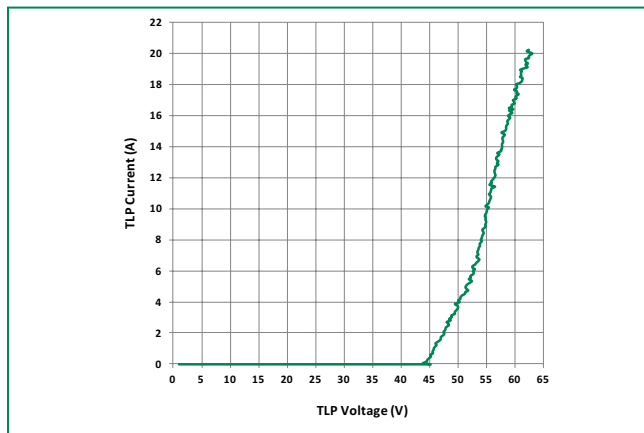
SD15C Transmission Line Pulsing(TLP) Plot



SD24C Transmission Line Pulsing(TLP) Plot

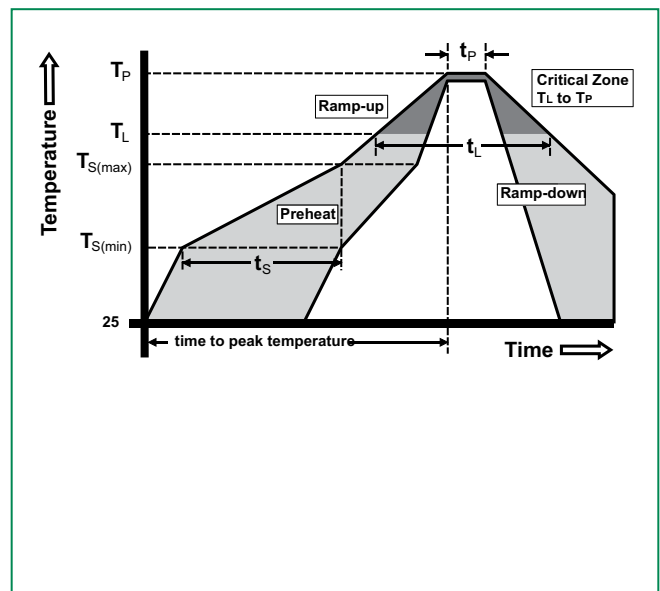


SD36C Transmission Line Pulsing(TLP) Plot



Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C



Product Characteristics

Lead Plating	Matte Tin
Lead Material	Copper Alloy
Lead Coplanarity	0.0004 inches (0.102mm)
Substrate material	Silicon
Body Material	Molded Epoxy
Flammability	UL 94 V-0

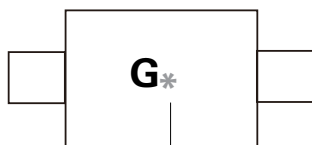
Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Bld is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

Ordering Information

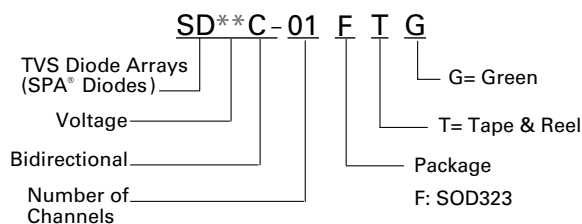
Part Number	Package	Marking	Min. Order Qty.
SD05C-01FTG	SOD323	G	3000
SD12C-01FTG	SOD323	G1	3000
SD15C-01FTG	SOD323	G2	3000
SD24C-01FTG	SOD323	G3	3000
SD36C-01FTG	SOD323	G4	3000

Part Marking System

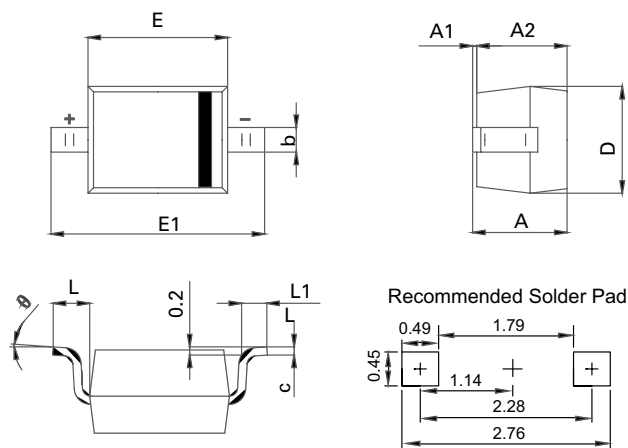


Blank: SD05C-01FTG
 1: SD12C-01FTG
 2: SD15C-01FTG
 3: SD24C-01FTG
 4: SD36C-01FTG

Part Numbering System



Package Dimensions -SOD323



Unit: mm

Symbol	SOD323			
	Millimeters		Inches	
	Min	Max	Min	Max
A		1.00		0.039
A1	0.00	0.10	0.000	0.004
A2	0.80	0.90	0.031	0.035
b	0.25	0.35	0.010	0.014
c	0.08	0.15	0.003	0.006
D	1.20	1.40	0.047	0.055
E	1.60	1.80	0.063	0.071
E1	2.50	2.70	0.098	0.106
L	0.475 REF		0.019 REF	
L1	0.25	0.40	0.010	0.016
Ø	0°	8°	0°	8°

Technical drawing of a circular mechanical part, showing multiple views and dimensions:

- Top View:** Shows the overall circular shape with a diameter of $\varnothing 178$. It features a central hub with a diameter of $\varnothing 1.50$ and four radial spokes. The outer edge has a radius of $R25.6$. The central hub has a radius of $R25.6$ and a central hole with a diameter of $\varnothing 1.50$. The distance between the centers of the two outermost holes is 4.00 . The distance between the centers of the two innermost holes is 2.00 . The total width of the part is 8.00 . The distance from the center of the part to the center of the outermost hole is 3.50 . The distance from the center of the part to the center of the innermost hole is 1.75 . The part is labeled with "A" and "B" at the bottom.
- Front View:** Shows the part from the side, with a total height of 12.3 . The distance from the top surface to the center of the part is 6.4 . The distance from the bottom surface to the center of the part is 9.5 . The part is labeled with "A" and "B" at the bottom.
- Section A-A:** A cross-section view showing the internal structure of the part. The total height is 0.254 . The distance from the top surface to the center of the part is 1.46 . The part is labeled "A-A" at the bottom.
- Section B-B:** A cross-section view showing the internal structure of the part. The total height is 2.90 . The distance from the top surface to the center of the part is 1.25 . The part is labeled "B-B" at the bottom.
- Detail View:** A close-up view of the central hub, showing the $\varnothing 1.50$ hole and the $R25.6$ radius. The part is labeled "Cover Tape" at the bottom.